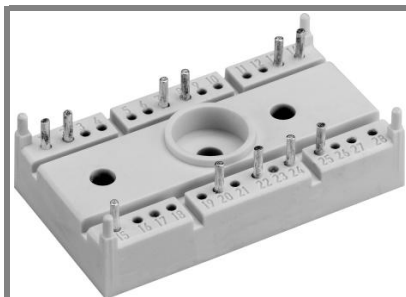


# SK 74 DGL 063



SEMITOP® 3

## 3-phase bridge rectifier + brake chopper

SK 74 DGL 063

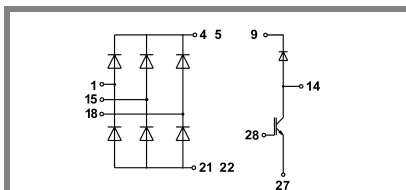
Target Data

### Features

- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- Ultrafast NPT technology IGBT
- CAL Technology FW

### Typical Applications

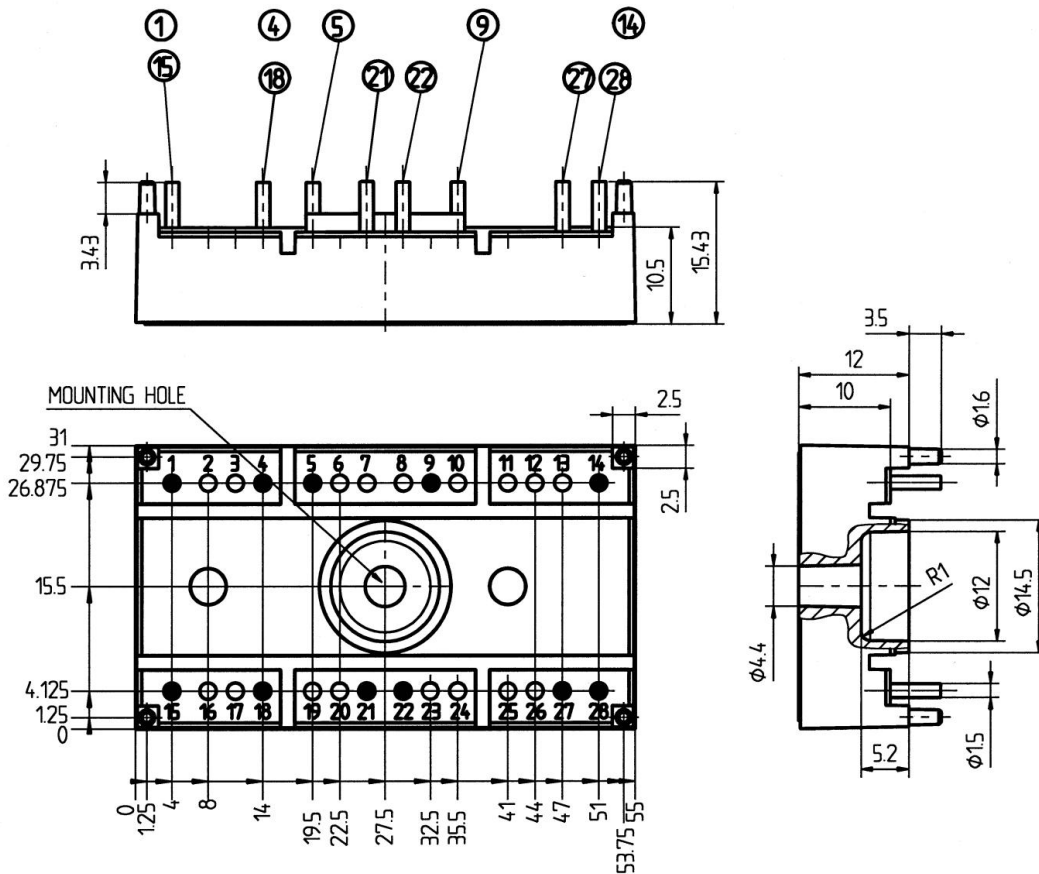
- Rectifier



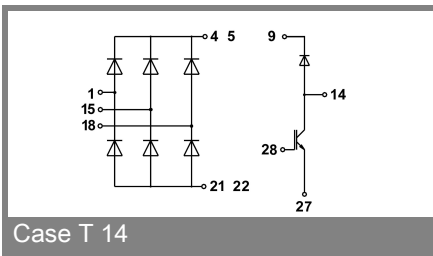
DGL

Absolute Maximum Ratings		$T_s = 25^\circ\text{C}$ , unless otherwise specified	
Symbol	Conditions	Values	Units
<b>IGBT - Chopper</b>			
$V_{CES}$		600	V
$I_C$	$T_s = 25 (80)^\circ\text{C}$	45 (32)	A
$I_{CM}$	$T_s = 25 (80)^\circ\text{C}$ , $t_p \leq 1 \text{ ms}$	90 (64)	A
$V_{GES}$		$\pm 20$	V
$T_j$		-40 ... +150	$^\circ\text{C}$
<b>Diode - Chopper</b>			
$I_F$	$T_s = 25 (80)^\circ\text{C}$	36 (24)	A
$I_{FM} = -I_{CM}$	$T_s = 25 (70)^\circ\text{C}$ , $t_p \leq 1 \text{ ms}$	72 (48)	A
$T_j$		-40 ... +150	$^\circ\text{C}$
<b>Rectifier</b>			
$V_{RRM}$		800	V
$I_{FAV} / I_{TAV}$	$T_s = 80^\circ\text{C}$	29	A
$I_{FSM} / I_{TSM}$	$t_p = 10 \text{ ms}$ , $\sin 180^\circ$ , $T_j = 25^\circ\text{C}$	370	A
$I_t^2$	$t_p = 10 \text{ ms}$ , $\sin 180^\circ$ , $T_j = 25^\circ\text{C}$	685	$\text{A}^2\text{s}$
$T_j$		-40 ... +150	$^\circ\text{C}$
$T_{sol}$	Terminals, 10s	260	$^\circ\text{C}$
$T_{stg}$		-40 ... +125	$^\circ\text{C}$
$V_{isol}$	AC, 1 min. / 1s	2500 / 3000	V

Characteristics		$T_s = 25^\circ\text{C}$ , unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
<b>IGBT - Chopper</b>					
$V_{CEsat}$	$I_C = 30 \text{ A}$ , $T_j = 25 (125)^\circ\text{C}$		1,8 (2)	2,1 (2,3)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}$ , $I_C = 0,5 \text{ mA}$	3	4	5	V
$V_{CE(TO)}$	$T_j = 25^\circ\text{C}$ (125) $^\circ\text{C}$		0,85 (0,9)		V
$r_T$	$T_j = 25^\circ\text{C}$ ( $^\circ\text{C}$ )				$\text{m}\Omega$
$C_{ies}$	$V_{CE} = 25 \text{ V}$ , $V_{GE} = 0 \text{ V}$ , $f = 1 \text{ MHz}$		2,6		nF
$C_{oes}$	$V_{CE} = V_{GE} = 0 \text{ V}$ , $f = 1 \text{ MHz}$		-		nF
$C_{res}$	$V_{CE} = V_{GE} = 0 \text{ V}$ , $f = 1 \text{ MHz}$		-		nF
$R_{th(j-s)}$	per IGBT			1	K/W
$t_{d(on)}$	under following conditions		45		ns
$t_r$	$V_{CC} = 300 \text{ V}$ , $V_{GE} = \pm 15 \text{ V}$		40		ns
$t_{d(off)}$	$I_C = 30 \text{ A}$ , $T_j = 125^\circ\text{C}$		250		ns
$t_f$	$R_{Gon} = R_{Goff} = 22 \Omega$		30		ns
$E_{on}$	inductive load		1,45		mJ
$E_{off}$			1,2		mJ
<b>Diode - Chopper</b>					
$V_F = V_{EC}$	$I_F = 25 \text{ A}$ , $T_j = 25 (125)^\circ\text{C}$		1,45 (1,4)	1,7 (1,75)	V
$V_{(TO)}$	$T_j = 25^\circ\text{C}$ (125) $^\circ\text{C}$		(0,85)	(0,9)	V
$r_T$	$T_j = 25^\circ\text{C}$ (125) $^\circ\text{C}$		(22)	(16)	$\text{m}\Omega$
$R_{th(j-s)}$	per diode			1,7	K/W
$I_{RRM}$	under following conditions		16		A
$Q_{rr}$	$I_F = 25 \text{ A}$ , $V_R = 300 \text{ V}$		2		$\mu\text{C}$
$E_{rr}$	$V_{GE} = 0 \text{ V}$ , $T_j = 125^\circ\text{C}$		25		mJ
	$di_F/dt = 500 \text{ A}/\mu\text{s}$				
<b>Diode rectifier</b>					
$V_F$	$I_F = 25 \text{ A}$ , $T_j = 25^\circ\text{C}$		1,25		V
$V_{(TO)}$	$T_j = 150^\circ\text{C}$		0,8		V
$r_T$	$T_j = 150^\circ\text{C}$		13		$\text{m}\Omega$
$R_{th(j-s)}$	per diode			1,7	K/W
<b>Temperatur sensor</b>					
$R_{ts}$	%, $T_r = ( )^\circ\text{C}$		( )		$\Omega$
<b>Mechanical data</b>					
w			30		g
$M_s$	Mounting torque			2,5	Nm



Case T 14 (Suggested hole diameter, in the PCB, for solder pins and plastic mounting pins: 2mm)



Case T 14

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

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